

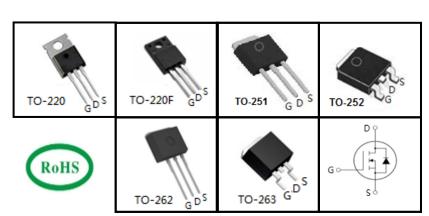
# **650V Super-Junction Power MOSFET**

#### **FEATURES**

- $\bullet \quad \text{Very low FOM R}_{\text{DS(on)}} \times \text{Q}_{\text{g}} \\$
- 100% avalanche tested
- RoHS compliant

#### **APPLICATIONS**

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)



Device Marking and Package Information						
Device	TPA65R280D	TPB65R280D	TPC65R280D	TPD65R280D	TPP65R280D	TPU65R280D
Package	TO-220F	TO-263	TO-262	TO-252	TO-220	TO-251
Marking	65R280D	65R280D	65R280AD	65R280AD	65R280AD	65R280AD

<b>Absolute Maximum Ratings</b> $T_C = 25^{\circ}C$ , unless otherwise noted						
_		Value				
Parameter	Symbol	TO-220F	TO-220, TO-251, TO-262, TO-2		Unit	
Drain-Source Voltage (V <sub>GS</sub> = 0V)	V <sub>DSS</sub>		650		V	
Continuous Drain Current	I <sub>D</sub>	15		Α		
Pulsed Drain Current (note1	I <sub>DM</sub>	45		Α		
Gate-Source Voltage	V <sub>GSS</sub>	±30		V		
Single Pulse Avalanche Energy (note2	) E <sub>AS</sub>	290 n		mJ		
Avalanche Current (note1	) I <sub>AS</sub>	2.4		Α		
MOSFET dv/dt ruggedness, V <sub>DS</sub> = 0480V	dv/dt	50			V/ns	
Reverse diode dv/dt, $V_{DS} = 0480V$ , $I_{SD} \le I_{D}$	dv/dt	15			V/ns	
Power Dissipation (T <sub>C</sub> = 25°C)	P <sub>D</sub>	32 104		W		
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55~+150			°C	

Thermal Resistance					
			Value		
Parameter	Symbol	TO-220F	TO-220, TO-251, TO-252 TO-262, TO-263	Unit	
Thermal Resistance, Junction-to-Case	R <sub>thJC</sub>	3.9	1.2	00.00	
Thermal Resistance, Junction-to-Ambient	R <sub>thJA</sub>	80	62	°C/W	

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## TPA65R280D, TPB65R280D, TPC65R280D, TPD65R280D, TPP65R280D, TPU65R280D

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<b>Specifications</b> T <sub>J</sub> = 25°C, ur	1033 01110					
Parameter	Symbol Test Conditions -		Value		Unit	
			Min.	Тур.	Max.	
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_{D} = 250\mu A$	650			V
Zero Gate Voltage Drain Current	$I_{DSS}$ $V_{DS} = 650V, V_{GS} = 0V, T_{J} = 25^{\circ}C$ $V_{DS} = 650V, V_{GS} = 0V, T_{J} = 150^{\circ}C$	$V_{DS} = 650V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μA
		$V_{DS} = 650V, V_{GS} = 0V, T_{J} = 150^{\circ}C$			100	μ, ,
Gate-Source Leakage	$I_{GSS}$	$V_{GS} = \pm 30V$			±100	nA
Gate-Source Threshold Voltage	$V_{\rm GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.5		4.0	V
Drain-Source On-Resistance (Note3)	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 7.5A$		0.23	0.28	Ω
Forward Transconductance (Note3)	$g_{fs}$	$V_{DS} = 10V, I_{D} = 7.5A$		10		S
Dynamic				-	-	
Input Capacitance	C <sub>iss</sub>	V - 0V		1250		pF
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0V,$ $V_{DS} = 50V,$		81		
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1.0MHz		7.1		
Total Gate Charge	$Q_g$			30		nC
Gate-Source Charge	$Q_{gs}$	$V_{DD} = 520V, I_{D} = 15A,$ $V_{GS} = 10V$		9		
Gate-Drain Charge	$Q_{gd}$			10		
Turn-on Delay Time	t <sub>d(on)</sub>			42		
Turn-on Rise Time	t <sub>r</sub>	$V_{DD} = 400V, I_{D} = 15A,$		17		
Turn-off Delay Time	t <sub>d(off)</sub>	$R_G = 25\Omega$		135		ns
Turn-off Fall Time	t <sub>f</sub>			6		
Drain-Source Body Diode Characteris	stics					
Continuous Body Diode Current	I <sub>s</sub>	T 0500			15	Α.
Pulsed Diode Forward Current	I <sub>SM</sub>	$T_C = 25^{\circ}C$			45	А
Body Diode Voltage	V <sub>SD</sub>	$T_J = 25^{\circ}\text{C}, I_{SD} = 15\text{A}, V_{GS} = 0\text{V}$		0.9	1.2	V
Reverse Recovery Time	t <sub>rr</sub>			335		ns
Reverse Recovery Charge	Q <sub>rr</sub>	$V_R = 480V, I_F = I_S,$ $di_F/dt = 100A/\mu s$		3.4		μC
Peak Reverse Recovery Current	I <sub>rrm</sub>	3. <sub>F</sub> , 3. 1007 v <b>po</b>		20		Α

#### **Notes**

- 1. Repetitive Rating: Pulse Width limited by maximum junction temperature
- 2.  $I_{AS}$  = 2.4A,  $V_{DD}$  = 50V,  $R_{G}$  = 25 $\Omega$ , Starting  $T_{J}$  = 25 $^{\circ}$ C
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 1%

I<sub>D</sub>, Drain Current (A)

50

45

40

35

30

25

20

15

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Figure 2. Transfer Characteristics

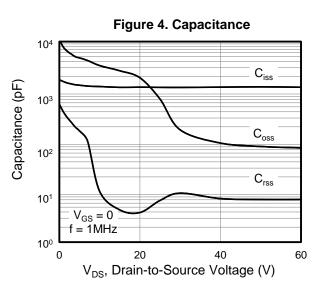
### **Typical Characteristics** $T_J = 25^{\circ}C$ , unless otherwise noted

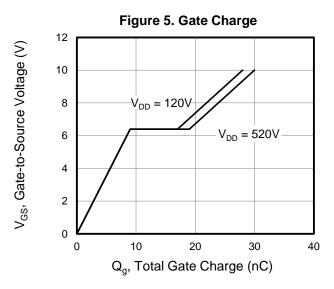
Figure 1. Output Characteristics 20V 10V 8V 6V 5V

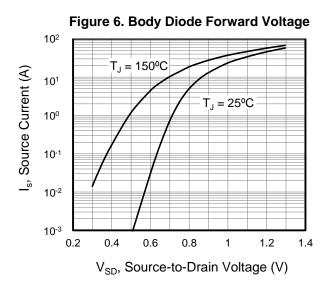
10 20 V<sub>DS</sub>, Drain-to-Source Voltage (V)

40  $T_{J} = 25^{\circ}C$  $V_{DS} = 10V$ 35 l<sub>D</sub>, Drain Current (A) 30 25  $T_{\rm J} = 150^{\rm o}{\rm C}$ 20 15 10 5 0 0 10 V<sub>GS</sub>, Gate-to-Source Voltage (V)

Figure 3. On-Resistance vs. Drain Current 0.29  $R_{DS(on)}$ , On-Resistance  $(\Omega)$  $V_{GS} = 10V$  $T_{J} = 25^{\circ}C$ 0.27 0.25 0.23 0.21 0.19 10 13 16 19 I<sub>D</sub>, Drain Current (A)







### **Typical Characteristics** $T_J = 25^{\circ}\text{C}$ , unless otherwise noted

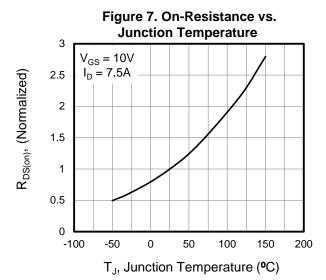


Figure 9. Transient Thermal Impedance TO-220,TO-251,TO-252,TO-262,TO-263

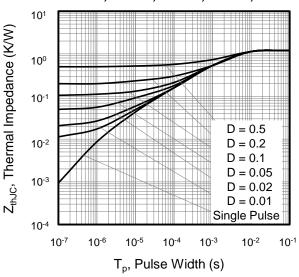


Figure 11. Safe operation area for

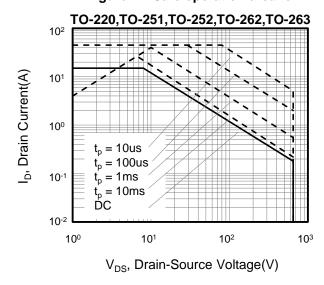


Figure 8. Threshold Voltage vs. Junction Temperature

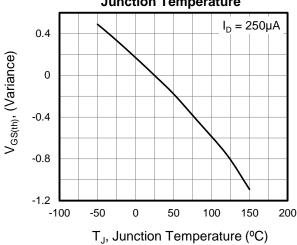


Figure 10. Transient Thermal Impedance TO-220F

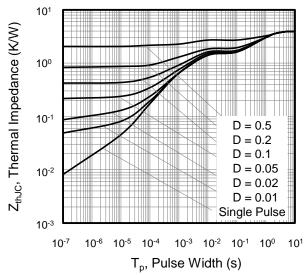


Figure 12. Safe operation area for

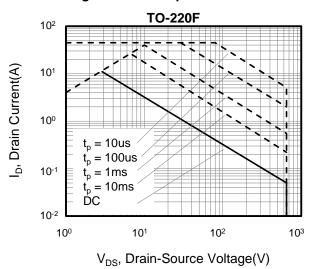




Figure A: Gate Charge Test Circuit and Waveform

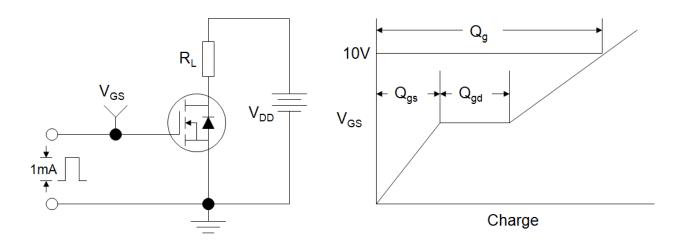


Figure B: Resistive Switching Test Circuit and Waveform

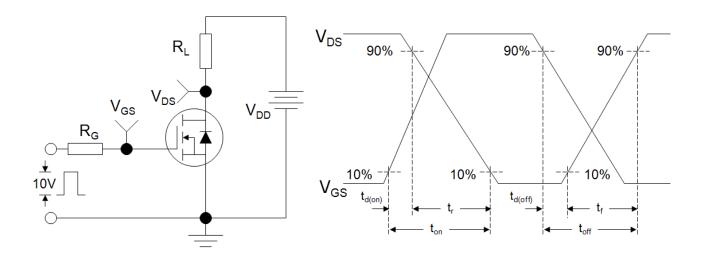
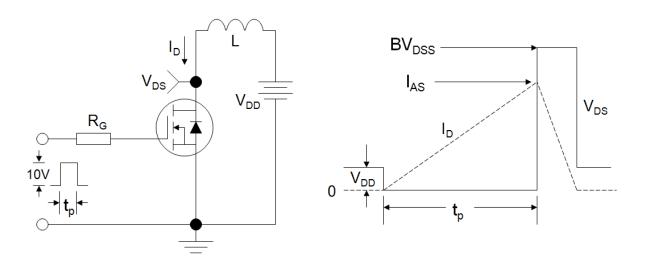
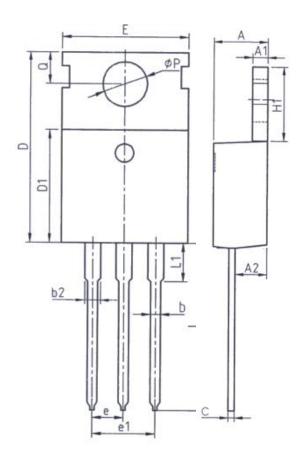


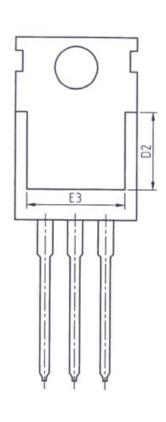
Figure C: Unclamped Inductive Switching Test Circuit and Waveform



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# **TO-220**

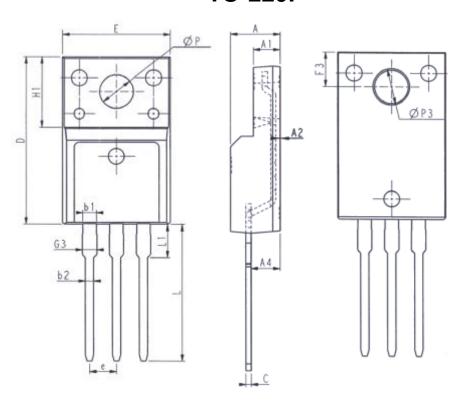




Unit: mm				
Symbol	Min.	Max.		
Α	4. 37	4. 77		
A1	1. 25	1. 45		
A2	2. 20	2. 60		
b	0. 70	0. 95		
b2	1. 17	1. 47		
С	0.40	0. 65		
D	15. 10	16. 10		
D1	8. 80	9. 40		
D2	5. 50	_		

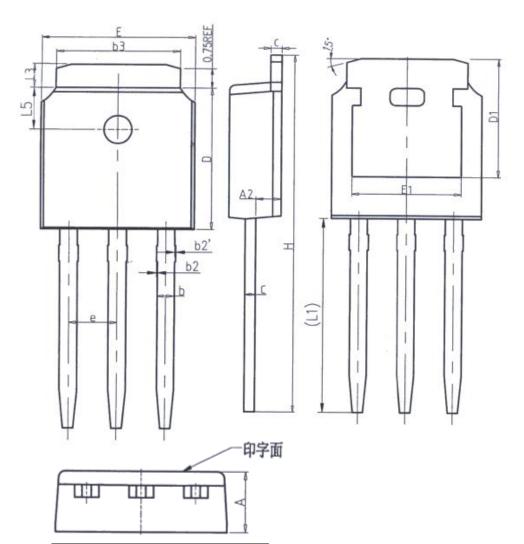
Unit: mm				
Symbol	Min.	Max.		
E	9. 70	10. 30		
E3	7. 00	-		
е	2. 54BSC			
e1	5. 08BSC			
H1	6. 25	6. 85		
L	12. 75	13.80		
L1	-	3. 40		
P	3. 40	3. 80		
Q	2. 60	3. 00		

**TO-220F** 



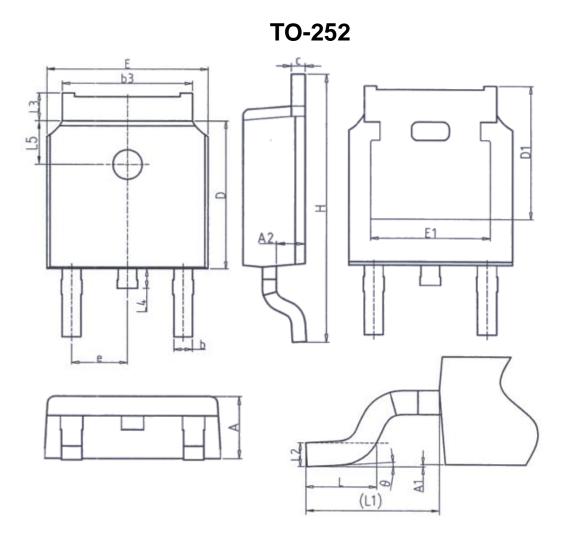
Unit: mm			l	Jnit: mm	1
Symbol	Min.	Max.	Symbol	Min.	Max.
E	9. 96	10.36	L	12. 68	13. 28
Α	4. 50	4. 90	L1	2. 93	3. 13
A1	2. 34	2. 74	Р	3. 03	3. 38
A2	0. 30	0.60	Р3	3. 15	3. 65
A4	2. 56	2. 96	F3	3. 15	3. 45
С	0.40	0. 65	G3	1. 25	1. 55
D	15. 57	16. 17	b1	1. 18	1. 43
H1	6. 70	REF	b2	0. 70	0. 95
е	2. 54	4BSC			

# **TO-251**



Unit: mm				
Symbol	Min.	Max.		
Α	2. 20	2. 40		
A2	0. 97	1. 17		
b	0. 68	0. 90		
b2	0.00	0.10		
b2′	0.00	0.10		
b3	5. 20	5. 50		
С	0. 43	0. 63		
D	5. 98	6. 22		

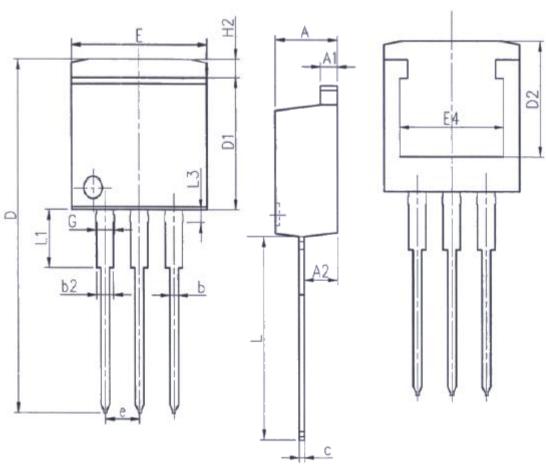
Unit: mm				
Symbol	Min.	Max.		
D1	5. 30	REF		
E	6. 40	6. 80		
E1	4. 63	-		
е	2. 286BSC			
Н	16. 22	16. 82		
L1	9. 15	9. 65		
L3	0.88	1. 28		
L5	1. 65	1. 95		



Unit: mm					
Symbol	Min.	Max.			
Α	2. 20	2. 40			
A1	0.00	0. 20			
A2	0. 97	1. 17			
b	0. 68	0. 90			
b3	5. 20	5. 50			
С	0. 43	0. 63			
D	5. 98	6. 22			
D1	5. 30REF				
E	6. 40	6. 80			
E1	4. 63	-			

Unit: mm				
Symbol	Min.	Max.		
е	2. 28	6BSC		
Н	9. 40	10.50		
L	1. 38	1. 75		
L1	2. 90REF			
L2	0. 51	IBSC		
L3	0.88	1. 28		
L4	- 1.00			
L5	1. 65	1. 95		
θ	0°	8°		

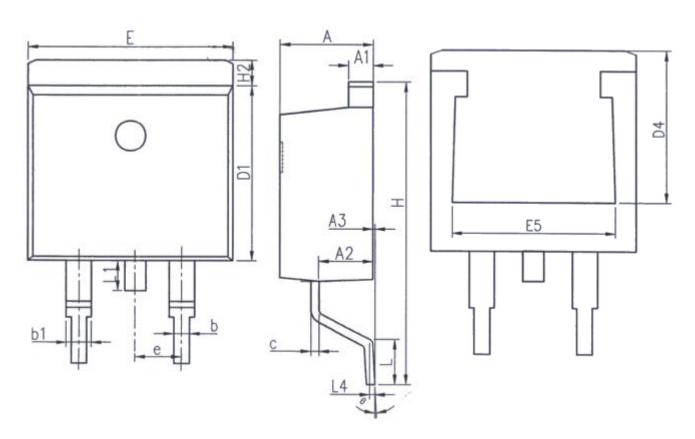




Unit: mm				
Symbol	Min.	Max.		
Α	4. 37	4. 77		
A1	1. 22	1. 42		
A2	2. 47	2. 87		
b	0. 70	0. 97		
b2	1. 17	1. 42		
С	0. 28	0.53		
D	23. 20	24. 02		
D1	8. 38	8. 90		
D2	6. 00	_		

Unit: mm			
Symbol	Min.	Max.	
E	9. 90	10.39	
E4	7. 30	_	
е	2. 54BSC		
G	1. 25	1.50	
H2	-	1. 31	
L	13. 34	14. 10	
L1	3. 30	4. 06	
L3	0. 95	1. 15	

# **TO-263**



Unit: mm		
Symbol	Min.	Max.
Α	4. 37	4. 77
<b>A</b> 1	1. 22	1. 42
A2	2. 49	2. 89
A3	0.00	0. 25
b	0. 70	0. 96
b1	1. 17	1. 47
С	0. 30	0. 53
D1	8. 50	8. 90
D4	6. 60	_

Unit: mm			
Symbol	Min.	Max.	
E	9.86	10.36	
<b>E</b> 5	7. 06	-	
е	2. 54BSC		
Н	14. 70	15. 50	
H2	1. 07	1. 47	
L	2.00	2. 60	
L1	1. 40	1. 70	
L4	0. 25BSC		
θ	0°	9°	



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